

FYPF1010DN

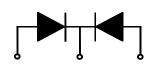
Features

- · Low forward voltage drop
- High frequency properties and switching speed
- Guard ring for over-voltage protection

Applications

- Switched mode power supply
- Freewheeling diodes





1. Anode 2. Cathode 3. Anode

SCHOTTKY BARRIER RECTIFIER

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{RRM}	Maximum Repetitive Reverse Voltage	100	V
V _R	Maximum DC Reverse Voltage	100	V
I _{F(AV)}	Average Rectified Forward Current @ T _C = 125°C	10	Α
I _{FSM}	Non-repetitive Peak Surge Current (per diode) 60Hz Single Half-Sine Wave	100	А
T _{J,} T _{STG}	Operating Junction and Storage Temperature	-40 to +150	°C

Thermal Characteristics

Symbol Parameter		Value	Units
$R_{\theta,IC}$	Maximum Thermal Resistance, Junction to Case (per diode)	4.0	°C/W

Electrical Characteristics (per diode)

Symbol	Parameter		Value	Units	
V _{FM} *	Maximum Instantaneous Forward Voltage			V	
	I _F = 5A	$T_C = 25 ^{\circ}C$	0.75		
	I _F = 5A	$T_C = 25 ^{\circ}C$ $T_C = 125 ^{\circ}C$	0.65		
	I _F = 10A	$T_{C} = 25 ^{\circ}\text{C}$ $T_{C} = 125 ^{\circ}\text{C}$	0.95		
	I _F = 10A	T _C = 125 °C	0.73		
I _{RM} * Maximum Instantaneous Reverse Current				mA	
	@ rated V _R	$T_C = 25 ^{\circ}C$	1		
	·	$T_C = 25 ^{\circ}C$ $T_C = 125 ^{\circ}C$	30		

^{*} Pulse Test: Pulse Width=300µs, Duty Cycle=2%

Typical Characteristics

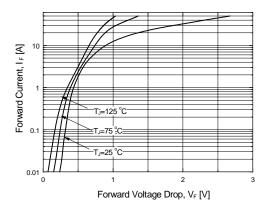


Figure 1. Typical Forward Voltage Characteristics (per diode)

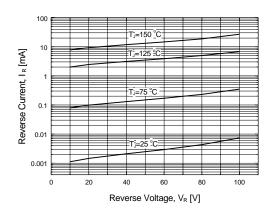


Figure 2. Typical Reverse Current vs. Reverse Voltage (per diode)

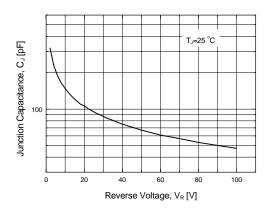


Figure 3. Typical Junction Capacitance (per diode)

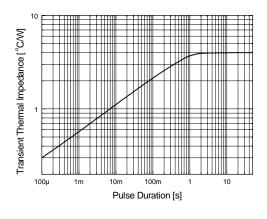


Figure 4. Thermal Impedance Characteristics (per diode)

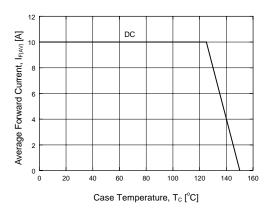


Figure 5. Forward Current Derating Curve

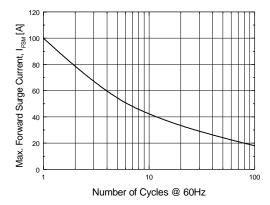
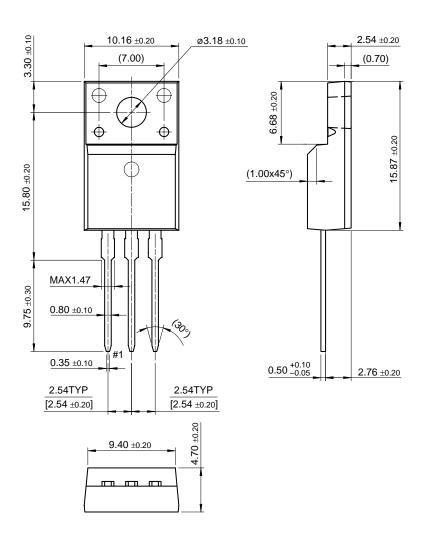


Figure 6. Non-Repetive Sureg Current (per diode)

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Package Dimensions

TO-220F



Dimensions in Millimeters

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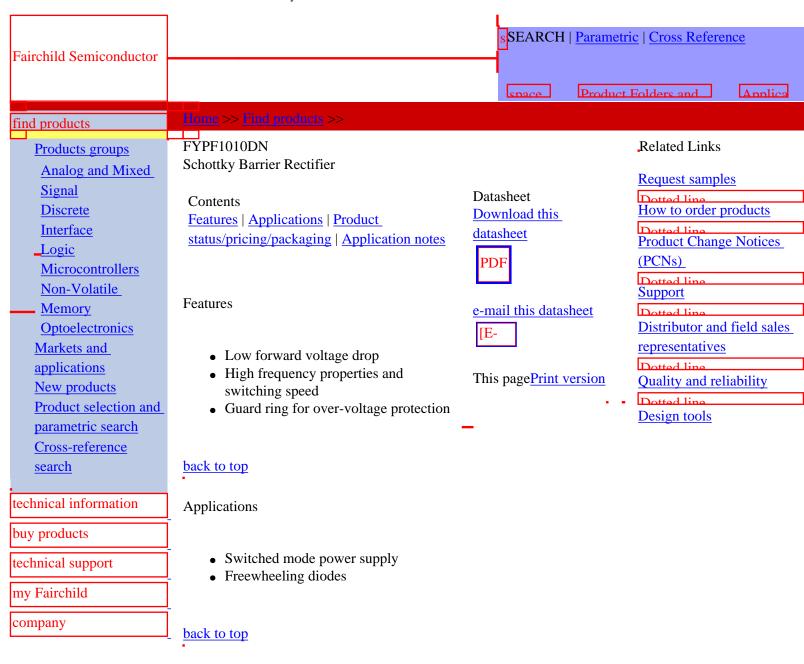
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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
FYPF1010DNTU	Full Production	\$0.60	<u>TO-220F</u>	3	RAIL

^{* 1,000} piece Budgetary Pricing

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Application notes

AN-9015: AN-9015 A180W, 100KHz Forward Converter Using QFET (65 K) Jul 19, 2002

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Product Folder - Fairchild P/N FYPF1010DN - Schottky Barrier Rectifier

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